

TOSHIBA Variable Capacitance Diode Silicon Epitaxial Planar Type

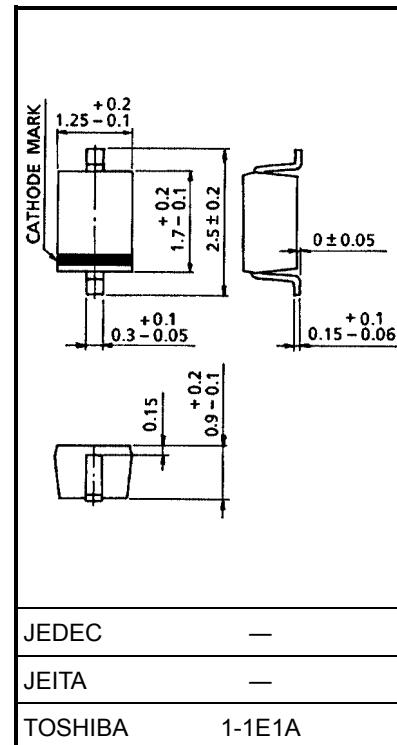
1SV216

TV VHF UHF Tuner AFC

Unit: mm

Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Reverse voltage	V _R	30	V
Peak reverse voltage	V _{RM}	35 (R _L = 10 kΩ)	V
Junction temperature	T _j	125	°C
Storage temperature range	T _{stg}	-55~125	°C

**Electrical Characteristics (Ta = 25°C)**

Weight: 0.004 g (typ.)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Reverse voltage	V _R	I _R = 1 μA	30	—	—	V
Reverse current	I _R	V _R = 28 V	—	—	10	nA
Capacitance	C _{2V}	V _R = 2 V, f = 1 MHz	10.5	—	16	pF
Capacitance	C _{10V}	V _R = 10 V, f = 1 MHz	3.3	—	5.7	pF
Capacitance ratio	C _{2V} /C _{10V}	—	2.5	—	3.4	—
Series resistance	r _s	V _R = 5 V, f = 470 MHz	—	0.55	1.2	Ω

Marking